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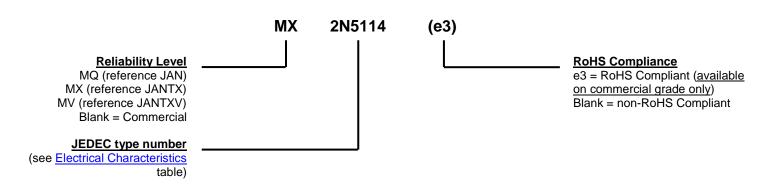
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MECHANICAL and PACKAGING

- CASE: Hermetically sealed, Nickel plated Kovar Base, Nickel Cap.
- TERMINALS: Gold plate over nickel, Kovar, Solder dipped. RoHS compliant Matte/Tin plating available on commercial grade only.
- MARKING: Part Number, Data Code, Manufacturer's ID.
- WEIGHT: Approximately 0.3 grams.
- See <u>Package Dimensions</u> on last page.

PART NOMENCLATURE





ELECTRICAL CHARACTERISTICS @ $T_A = +25^{\circ}C$ unless otherwise noted.

Parameters / Test Conditions		Symbol	Min.	Max.	Unit
Gate-Source Breakdown Voltage $V_{DS} = 0, I_G = 1.0 \ \mu A$		V _{(BR)GSS}	30		V
Drain-Source "On" State Voltage $V_{GS} = 0 \text{ V}, \text{ I}_{D} = -15 \text{ mA}$ $V_{GS} = 0 \text{ V}, \text{ I}_{D} = -7.0 \text{ mA}$ $V_{GS} = 0 \text{ V}, \text{ I}_{D} = -3.0 \text{ mA}$	2N5114 2N5115 2N5116	V _{DS(on)}		-1.3 -0.8 -0.6	V
Gate Reverse Current $V_{DS} = 0, V_{GS} = 20 V$		I _{GSS}		500	pА
	2N5114 2N5115 2N5116	I _{D(off)}		-500 -500 -500	pА
Zero Gate Voltage Drain Current $V_{GS} = 0$, $V_{DS} = -18V$ $V_{GS} = 0$, $V_{DS} = -15V$ $V_{GS} = 0$, $V_{DS} = -15V$	2N5114 2N5115 2N5116	I _{DSS}	-30 -15 -5.0	-90 -60 -25	mA
Gate-Source Cutoff $V_{DS} = -15$, $I_D = -1.0$ nA $V_{DS} = -15$, $I_D = -1.0$ nA $V_{DS} = -15$, $I_D = -1.0$ nA	2N5114 2N5115 2N5116	V _{GS(off)}	5.0 3.0 1.0	10 6.0 4.0	V

DYNAMIC CHARACTERISTICS

Parameters / Test Conditions Small-Signal Drain-Source "On" State Resistance		Symbol	Min.	Max.	Unit
$V_{GS} = 0, I_{D} = -1.0 \text{ mA}$	2N5114 2N5115 2N5116	r _{ds(on)1}		75 100 175	Ω
Small-Signal Drain-Source "On" State Re					
$V_{GS} = 0, I_D = 0; f = 1 \text{ kHz}$	2N5114 2N5115 2N5116	r _{ds(on)2}		75 100 175	Ω
Small-Signal, Common-Source Short-Cir Capacitance	cuit Reverse Transfer				
	2N5114 2N5115 2N5116	C _{rss}		7.0	pF
Small-Signal, Common-Source Short-Cir $V_{GS} = 0$, $V_{DS} = -15$ V, f = 1.0 MHz	cuit Input Capacitance 2N5114, 2N5115 2N5116	C _{iss}		25 27	pF



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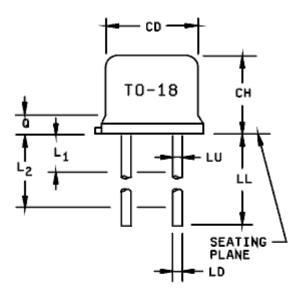
ELECTRICAL CHARACTERISTICS @ $T_A = +25^{\circ}C$ unless otherwise noted. (continued)

Parameters / Test Conditions		Symbol	Min.	Max.	Unit
Turn-On Delay Time	2N5114 2N5115 2N5116	T _{d(on)}	6 10 25	10	ηs
Rise Time	2N5114 2N5115 2N5116	tr		10 20 35	ηs
Turn-Off Delay Time	2N5114 2N5115 2N5116	T _{d(off)}		6 8 20	ηs

T4-LDS-0006, Rev. 2 (111983)



PACKAGE DIMENSIONS



HD

Dimensions					
Symbol	Inches		Millimeters		Note
-	Min	Max	Min	Max	
CD	.178	.195	4.52	4.95	
CH	.170	.210	4.32	5.33	
HD	.209	.230	5.31	5.84	
LC	.100	.100 TP		2.54 TP	
LD	.016	.021	0.41	0.53	7,8
LL	.500	.750	12.70	19.05	7,8
LU	.016	.019	0.41	0.48	7,8
L1		.050		1.27	7,8
L2	.250		6.35		7,8
Q		.030		0.76	5
TL	.028	.048	0.71	1.22	3,4
TW	.036	.046	0.91	1.17	
r		.010		0.25	10
α	45° TP		45° TP		6
1, 2, 9, 11, 12					



NOTES:

- 1. Dimension are in inches.
- 2. Millimeters are given for general information only.
- 3. Beyond r (radius) maximum, TH shall be held for a minimum length of .011 inch (0.28 mm).
- 4. Dimension TL measured from maximum HD.
- 5. Body contour optional within zone defined by HD, CD, and Q.
- Leads at gauge plane .054 +.001 -.000 inch (1.37 +0.03 -0.00 mm) below seating plane shall be within .007 inch (0.18 mm) radius of true position (TP) at maximum material condition (MMC) relative to tab at MMC. The device may be measured by direct methods or by the gauge and gauging procedure shown in figure 2.
- 7. Dimension LU applies between L₁ and L₂. Dimension LD applies between L₂ and LL minimum. Diameter is uncontrolled in L₁ and beyond LL minimum.
- 8. All three leads.
- 9. The collector shall be internally connected to the case.
- 10. Dimension r (radius) applies to both inside corners of tab.
- 11. In accordance with ASME Y14.5M, diameters are equivalent to ϕx symbology.
- 12. Lead 1 =source, lead 2 =gate, lead 3 =drain.